

SKiIP 3-phase bridge

Absolute Maximum Ratings			
Symbol	Conditions ¹⁾	Values	Units
V_{isol} ⁴⁾	AC, 1min	3000	V
T_{op}, T_{stg}	Operating / stor. temperature	-25...+85	°C
IGBT and Inverse Diode			
V_{CES}		1200	V
V_{CC} ⁵⁾	Operating DC link voltage	900	V
I_C	IGBT	200	A
T_j ³⁾	IGBT + Diode	-40...+150	°C
I_F	Diode	200	A
I_{FM}	Diode, $t_p < 1$ ms	400	A
I_{FSM}	Diode, $T_j = 150$ °C, 10ms; sin	1440	A
I^2t (Diode)	Diode, $T_j = 150$ °C, 10ms	10	kAs ²
Driver			
V_{S1}	Stabilized Power Supply	18	V
V_{S2}	Non-stabilized Power Supply	30	V
f_{smax}	Switching frequency	20	kHz
dV/dt	Primary to secondary side	75	kV/ μ s

Characteristics		min.	typ.	max.	Units
Symbol	Conditions ¹⁾				
IGBT ¹¹⁾					
$V_{(BR)CES}$	Driver without supply	$\geq V_{CES}$	–	–	V
I_{CES}	$V_{GE} = 0, T_j = 25$ °C	–	–	0,4	mA
	$V_{CE} = V_{CES}, T_j = 125$ °C	–	10	–	mA
V_{TO}	$T_j = 125$ °C	–	–	1,38	V
r_T	$T_j = 125$ °C	–	–	10,5	m Ω
V_{Cesat}	$I_C = 175A, T_j = 125$ °C	–	–	3,2	V
V_{Cesat}	$I_C = 175A, T_j = 25$ °C	–	–	3,05	V
$E_{on} + E_{off}$	$V_{CC}=600/900V, I_C=200A$ $T_j = 125$ °C	–	–	60/98	mJ
C_{CHC}	per Phase, AC side	–	1,4	–	nF
L_{CE}	Top, Bottom	–	15	–	nH
Inverse Diode ²⁾					
$V_F = V_{EC}$	$I_F = 175A; T_j = 125$ °C	–	–	2,45	V
$V_F = V_{EC}$	$I_F = 175A; T_j = 25$ °C	–	–	2,55	V
$E_{on} + E_{off}$	$I_F = 200A; T_j = 125$ °C	–	–	8	mJ
V_{TO}	$T_j = 125$ °C	–	–	0,91	V
r_T	$T_j = 125$ °C	–	–	5,7	m Ω
Thermal Characteristics					
R_{thjs} ¹⁰⁾	per IGBT	–	–	0,129	K/W
R_{thjs} ¹⁰⁾	per Diode	–	–	0,375	K/W
R_{thsa} ^{6,10)}	P16 heatsink; see case S5	–	–	33	K/KW
Driver					
I_{S1}	Supply current 15V-supply	$340+360 \cdot f_s / f_{smax} + 3,5 \cdot I_{AC} / A$			mA
I_{S2}	Supply current 24V-supply	$250+240 \cdot f_s / f_{smax} + 2,6 \cdot I_{AC} / A$			mA
$t_{interlock-driver}$	Interlock-time	2,3			μ s
SKiIPPACK protection					
I_{TRIPSC}	Short circuit protection	250			A
I_{TRIPLG}	Ground fault protection	58			A
T_{TRIP}	Over-temp. protection	115			°C
$U_{DCT RIP}$ ⁹⁾	U_{DC} -protection	920			V
Mechanical Data					
M1	DC terminals, SI Units	4	–	6	Nm
M2	AC terminals, SI Units	8	–	10	Nm

SKiIPPACK®

SK integrated intelligent Power PACK

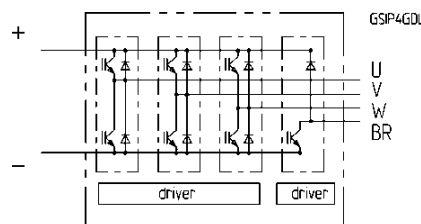
3-phase bridge with brake chopper (E/A)

SKiIP

232 GDL 120 - 410 CTV ^{7,9)}

Preliminary Data

Case S5



Features

- Short circuit protection, due to evaluation of current sensor signals
- Isolated power supply
- Low thermal impedance
- Optimal thermal management with integrated heatsink
- Pressure contact technology with increased power cycling capability, compact design
- Low stray inductance
- High power, small losses
- Over-temperature protection

- ¹⁾ $T_{heatsink} = 25$ °C, unless otherwise specified
- ²⁾ CAL = Controlled Axial Lifetime Technology (soft and fast)
- ³⁾ without driver
- ⁴⁾ Driver input to DC link / AC output to DC link / AC output to heatsink
- ⁵⁾ with Semikron-DC link (low inductance)
- ⁶⁾ other heatsinks on request
- ⁷⁾ C - Integrated current sensors
T - Temperature protection
V - 15 V or 24 V power supply options available for driver:
U - DC link voltage sense
F – Fiber optic connector
- ¹⁰⁾ “s” referenced to temperature sensor
- ¹¹⁾ NPT-technology with homogenous current-distribution

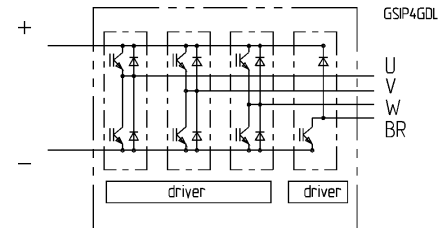
SKiIP Brake-chopper

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IGBT and Freewheeling Diode			
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V _{CC} ⁵⁾	Operating DC link voltage	900	V
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T _j ³⁾	IGBT + Diode	-40...+150	°C
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I _{FSM}	Diode, T _j = 150 °C, 10ms; sin	1440	A
I ² t (Diode)	Diode, T _j = 150 °C, 10ms	10	kAs ²
Driver			
V _{S1}	Stabilized Power Supply	18	V
V _{S2}	Non-stabilized Power Supply	30	V
f _{smax}	Switching frequency	5	kHz
dV/dt	Primary to secondary side	50	kV/μs

Characteristics		min.	typ.	max.	Units
Symbol	Conditions ¹⁾				
IGBT ¹¹⁾					
V _{(BR)CES}	Driver without supply	≥V _{CES}	–	–	V
I _{CES}	V _{GE} = 0, T _j = 25 °C	–	–	0,4	mA
	V _{CE} = V _{CES} T _j = 125 °C	–	10	–	mA
V _{TO}	T _j = 125 °C	–	–	1,38	V
r _T	T _j = 125 °C	–	–	10,5	mΩ
V _{Cesat}	I _C = 175A, T _j = 125 °C	–	–	3,2	V
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C _{CHC}	per SKiIP, AC side	–	1,4	–	nF
L _{CE}	Top, Bottom	–	15	–	nH
Freewheeling Diode ²⁾					
V _F = V _{EC}	I _F = 175A; T _j = 125 °C	–	–	2,45	V
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R _{thsa} ^{6,10)}	P16 heatsink; see case S5	–	–	33	K/KW
Driver					
I _{S1}	Supply current 15V-supply	67+10*f _s /f _{smax} +0*I _{AC} /A			mA
I _{S2}	Supply current 24V-supply	67+10*f _s /f _{smax} +0,0*I _{AC} /A			mA
t _{interlock-driver}	Interlock-time	2,3			μs
SKiIPPACK protection					
I _{TRIPSC}	Short circuit protection	V _{CESat} -protection			A
I _{TRIPLG}	Ground fault protection	-			A
T _{TRIP}	Over-temp. protection	115			°C
U _{DCTRIP} ⁹⁾	U _{DC} -protection	920			V
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- 3) without driver
- 4) Driver input to DC link / AC output to DC link / AC output to heatsink
- 5) with Semikron-DC link (low inductance)
- 6) other heatsinks on request
- 7) C - Integrated current sensors
T - Temperature protection
V - 15 V or 24 V power supply
- 8) E - adapted to 400 Vrms; U - adapted to 460 Vrms
- 9) options available for driver:
U - DC link voltage sense
F – Fiber optic connector
- 10) "s" referenced to temperature sensor
- 11) NPT-technology with homogeneous current-distribution

PIN-array - 3-phase bridge driver SKiPPACK type „GD and GDL”

X1:

Pin	signal	remark
1	shield	connected to GND, when shielded cable is used
2	BOT HB 1 IN ⁴⁾	positive 15V CMOS logic; 10 kΩ impedance
3	ERROR HB 1 OUT ¹⁾	short circuit monitoring HB1 LOW = NO ERROR; open collector output; max. 30 V / 15 mA propagation delay 1 μs, min. pulsewidth error-memory-reset 8 μs
4	TOP HB 1 IN ⁴⁾	positive 15V CMOS logic; 10 kΩ impedance
5	BOT HB 2 IN ⁴⁾	positive 15V CMOS logic; 10 kΩ impedance
6	ERROR HB 2 OUT ¹⁾	short circuit monitoring HB2 LOW = NO ERROR; open collector output; max. 30 V / 15 mA propagation delay 1 μs, min. pulsewidth error-memory-reset 8 μs
7	TOP HB 2 IN ⁴⁾	positive 15V CMOS logic; 10 kΩ impedance
8	BOT HB 3 IN ⁴⁾	positive 15V CMOS logic; 10 kΩ impedance
9	ERROR HB 3 OUT ¹⁾	short circuit monitoring HB 3 LOW = NO ERROR; open collector output; max. 30 V / 15 mA propagation delay 1 μs, min. pulsewidth error-memory-reset 8 μs
10	TOP HB 3 ⁴⁾	positive 15V CMOS logic; 10 kΩ impedance
11	Overtemp. OUT ¹⁾	LOW = NO ERROR = $\vartheta_{DCB} < 115 \pm 5^\circ\text{C}$ open collector Output; max. 30 V / 15 mA „low“ output voltage < 0,6 V „high“ output voltage max. 30 V
12	reserved	
13	U _{DC} analog OUT	U _{DC} when using option „U” actual DC-link voltage, 9,0 V refer to U _{DCmax} max. output current 5 mA
14	+ 24 V _{DC} IN	24 V _{DC} (20 - 30 V)
15	+ 24 V _{DC} IN	don't supply with 24 V, when using + 15 V _{DC} supply voltage monitoring threshold 15,6 V
16	+ 15 V _{DC} IN	15 V _{DC} ± 4 % power supply
17	+ 15 V _{DC} IN	don't supply with 15 V, when using + 24 V _{DCIN} supply voltage monitoring threshold 13 V
18	GND	GND for power supply and
19	GND	GND for digital signals
20	Temp. analog OUT	
21	GND aux ²⁾	
22	I analog OUT HB 1	current actual value, 8,0 V refer to 100 % I _C overcurrent trip level 10 V ⇔ 125 %; I _C @ 25 °C current value > 0 ⇔ SKiP is source current value < 0 ⇔ SKiP is sink
23	GND aux ²⁾	
24	I analog OUT HB 2	current actual value, 8,0 V refer to 100 % I _C overcurrent trip level 10 V ⇔ 125 %; I _C @ 25 °C current value > 0 ⇔ SKiP is source current value < 0 ⇔ SKiP is sink
25	GND aux ²⁾	
26	I analog OUT HB 3	current actual value, 8,0 V refer to 100 % I _C overcurrent trip level 10 V ⇔ 125 %; I _C @ 25 °C current value > 0 ⇔ SKiP is source current value < 0 ⇔ SKiP is sink

X10: halfbridge 1 (HB1) OUT

Pin	Signal
1	
2	
8	Collector 1=TOP (HB1)
11	Gate 1=TOP (HB1)
12	Emitter 1=TOP (HB1)
13	Collector 2=BOT (HB1)
16	Gate 2=BOT (HB1)
17	Emitter 2=BOT (HB1)

X11: halfbridge 2 (HB2) OUT

Pin	Signal
1	Temp.-Sensor (HB2)1
2	Temp.-Sensor (HB2)2
8	Collector 1=TOP (HB2)
11	Gate 1=TOP (HB2)
12	Emitter 1=TOP (HB2)
13	Collector 2=BOT (HB2)
16	Gate 2=BOT (HB2)
17	Emitter 2=BOT (HB2)

X12: halfbridge 3 (HB3) OUT

Pin	Signal
1	
2	
8	Collector 1=TOP (HB3)
11	Gate 1=TOP (HB3)
12	Emitter 1=TOP (HB3)
13	Collector 2=BOT (HB3)
16	Gate 2=BOT (HB3)
17	Emitter 2=BOT (HB3)

¹⁾ Open collector output, external pull up resistor necessary

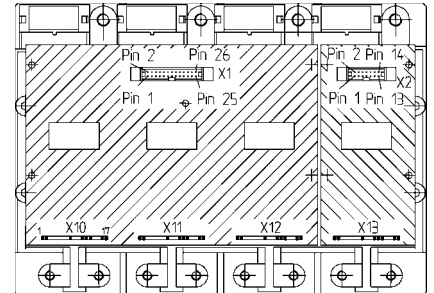
²⁾ GND aux = reference for analog output signals

⁴⁾ „high“ (min) 11,2 V
„low“ (max) 5,4 V

PIN-array - brake chopper driver (used in SKiiPPACK type GDL)

X2:

Pin	signal	remark
1	shield	connected to GND, when shielded cable is used
2	CHOPPER ext. ON	LOW = IGBT ON „low“ (max) 5 V, $I_{min} = 5 \text{ mA}$ „high“ (min) 11,5 V propagation delay $t_{d(on)} \leq 20 \mu\text{s}$ $t_{d(off)} \leq 25 \mu\text{s}$
3	ERROR OUT ¹⁾	LOW = NO ERROR open collector Output; max. 30 V / 2,5 mA propagation delay $t_{PD(on)error} \leq 60 \mu\text{s}$
4	RESET	LOW = RESET Reset-pulse-time $t_{PDRESET} > 300 \text{ ms}$ connect this pin to open collector output without pull up resistor „low“ (max) 2 V, „high“ (min) 12 V
5	reserved	
6	+ 24 V _{DC} IN	don't supply with 24 V, when using + 15 V _{DCIN}
7	+ 24 V _{DC} IN	supply voltage monitoring threshold 15,6 V
8	+ 15 V _{DC} IN	don't supply with 15 V, when using + 24 V _{DCIN}
9	+ 15 V _{DC} IN	supply voltage monitoring threshold 13 V
10	GND	
11	GND	
12	reserved	
13	reserved	
14	reserved	



X13: halfbridge (HB4) OUT

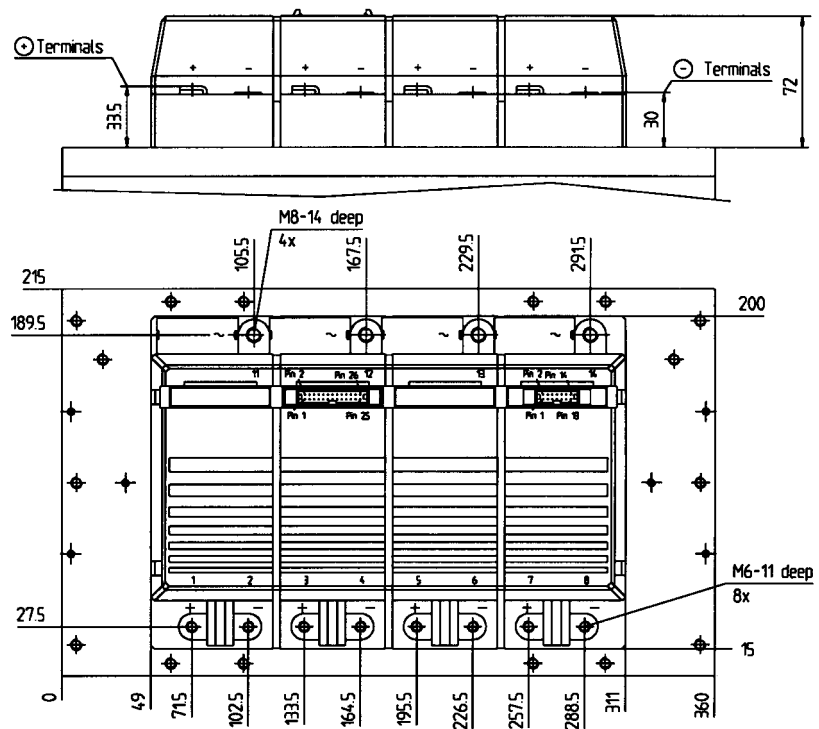
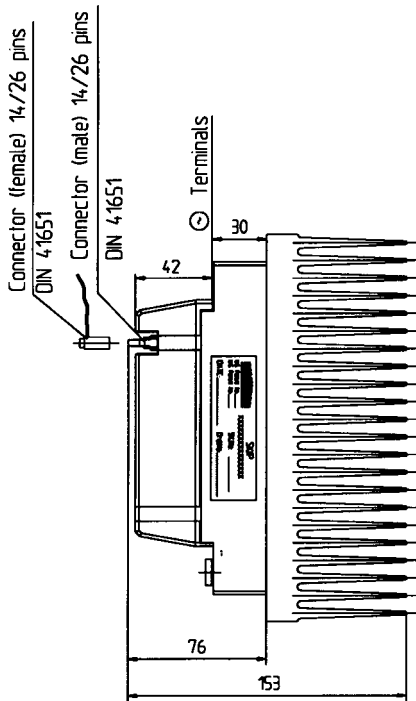
Pin	Signal	remark
1	Temp.-sensor	
2	Temp.-sensor	
8	Collector 1=TOP (HB4)	U_z monitoring
11	Gate 1=TOP (HB4)	connected with PIN 12
12	Emitter 1=TOP (HB4)	connected with PIN 11
13	Collector 2=BOT (HB4)	
16	Gate 2=BOT (HB4)	
17	Emitter 2=BOT (HB4)	

¹⁾ Open collector output, external pull up resistor necessary

Case S5

SKiiPPACK 4 - GDL

CASESSGDL



Weight without heatsink: 3,54 kg
 P16: 8,46 kg